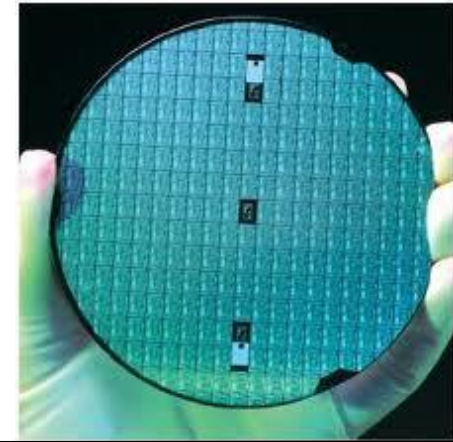
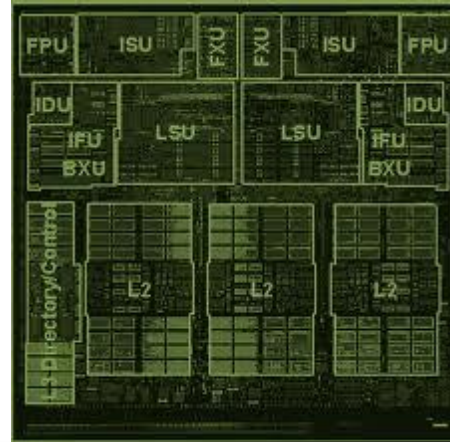
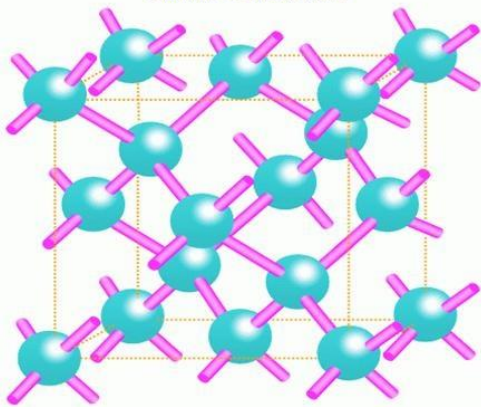


Structure of silicon crystal



# *ECE 122A*

# *VLSI Principles*

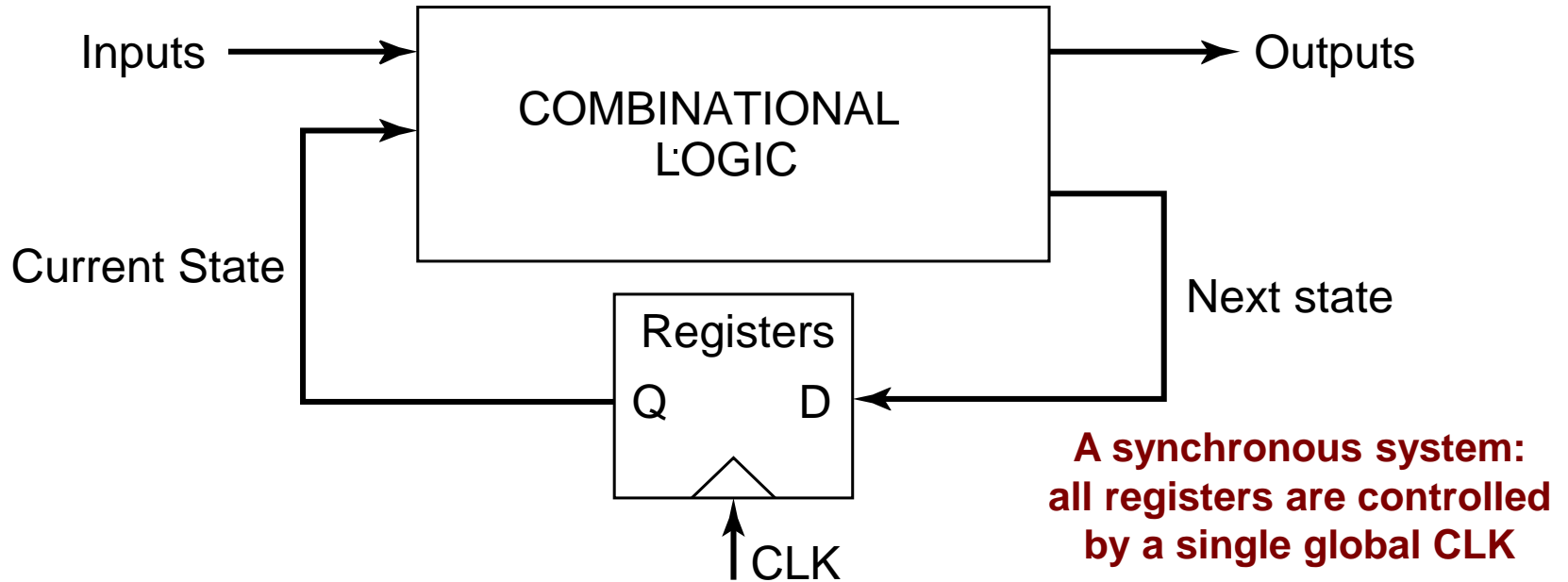
## *Lecture 15*

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Electrical and Computer Engineering  
University of California, Santa Barbara  
*E-mail: [kaustav@ece.ucsb.edu](mailto:kaustav@ece.ucsb.edu)*

# Designing Sequential Logic Circuits

# Sequential Logic

All useful systems require storage of state information....



A generic Finite State Machine (FSM) consisting of combinational logic and registers.

**Output of the FSM** =  $F(\text{current inputs, current state})$

**Next State** is determined based on current state and current inputs—fed to the input (D) of the registers

At the rising edge of the CLK, D copied to Q (with some delay)

**Note: There are 2 storage mechanisms: 1) positive feedback and 2) charge storage**

# *Classification of Memory Elements*

- Background Memory: large centralized memory core (high density array structures)---SRAMs and DRAMs
- Foreground Memory: embedded in a logic (individual registers or register banks)—**focus of this section**

# Classification of Memory Elements

## Static Memory:

- ❑ preserves state as long as **power is ON**
- ❑ built by using **positive feedback or regeneration** where the circuit consists of intentional connections between the output and input of a combinational circuit
- ❑ most useful when register will **not be updated for extended periods of time** (eg., configuration data loaded at power-up time).
- ❑ Condition also holds for most processors that use **conditional clocking**, (gated CLK) where the CLK is turned off for unused modules----**no guarantee on how frequently the registers will be clocked and static memories are needed to store information.**
- ❑ **bistable element** is the most popular form

# Classification of Memory Elements

## Dynamic Memory:

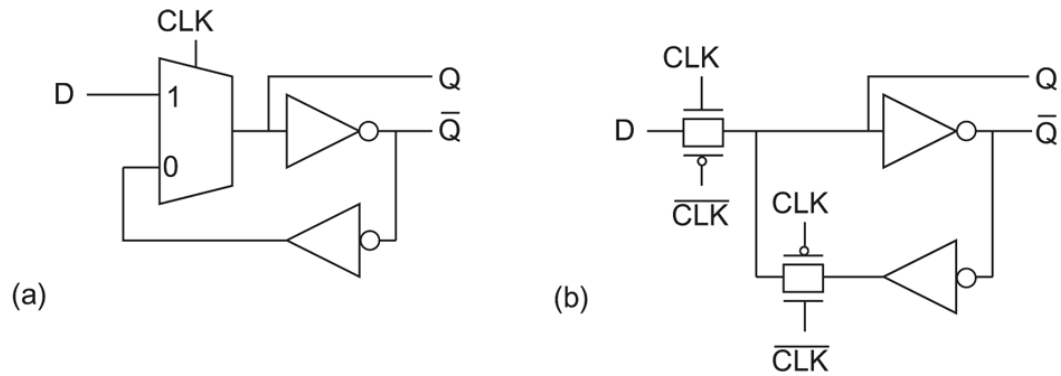
- ❑ store data for short (ms) period of time
- ❑ based on the principle of **temporary charge storage** on parasitic capacitors in MOS devices
- ❑ similar to **dynamic** logic..... capacitors need to be refreshed periodically to compensate for charge leakage
- ❑ significantly simpler----hence, provide **higher performance** and **lower power dissipation**
- ❑ most useful in **datapath circuits** that require higher performance levels and are **periodically clocked**

# Naming Conventions

- Definitions:
  - a latch is a **level sensitive device**
  - a register is an **edge-triggered storage element**
- There are many different naming conventions
  - For instance, many books call edge-triggered elements **flip-flops**
  - This may lead to confusion however...
  - Any **bistable** component formed by the cross coupling of gates is a **flip-flop** (FF)

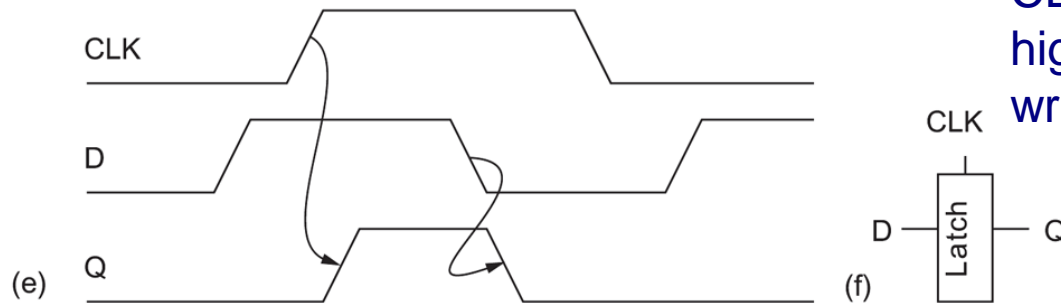
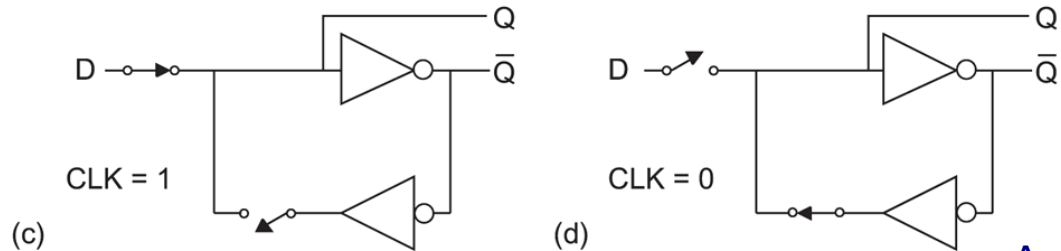
# Latches

## Multiplexer based



*CLK=1: D to Q*

*CLK=0: Holds state of Q*



As long as CLK remains high, D will be written on Q

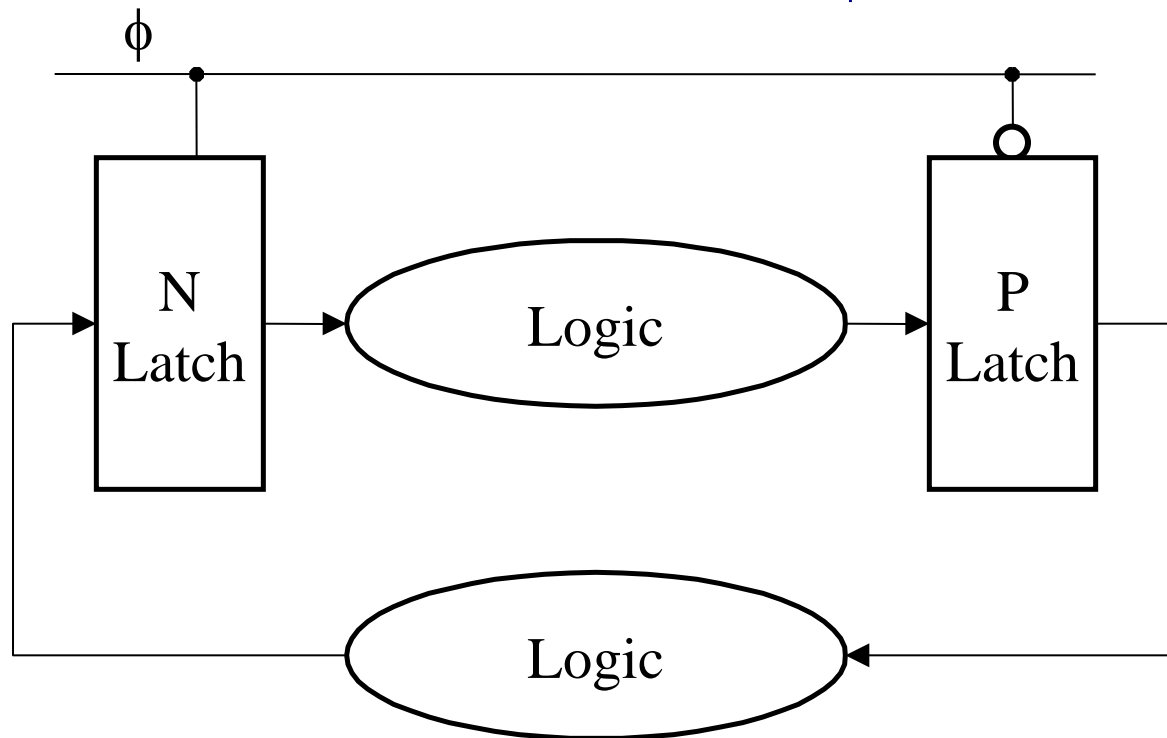
**FIG 1.30** CMOS positive-level-sensitive D latch



# Latch-Based Design

- N (negative) latch is transparent when  $\phi = 0$

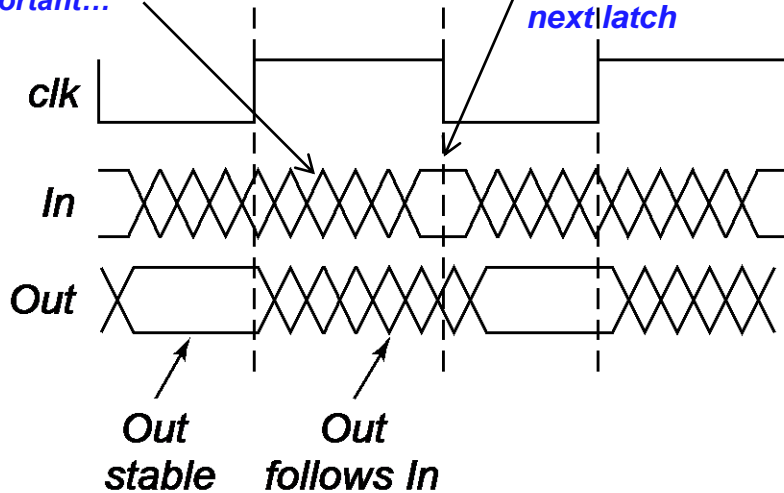
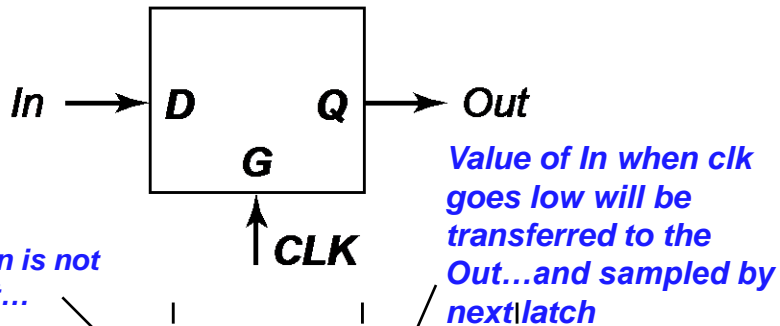
- P (positive) latch is transparent when  $\phi = 1$



***Difficult to eliminate Race conditions.....under CLK overlap***

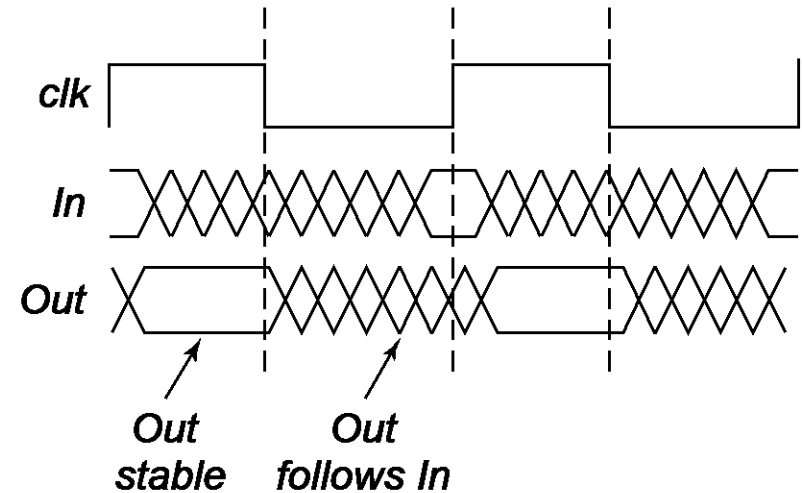
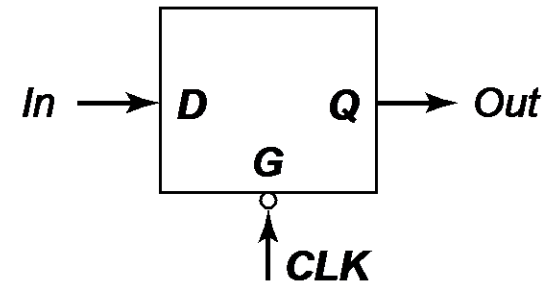
# Timing of P/N Latches

## Positive Latch



**When clk is high...**

## Negative Latch



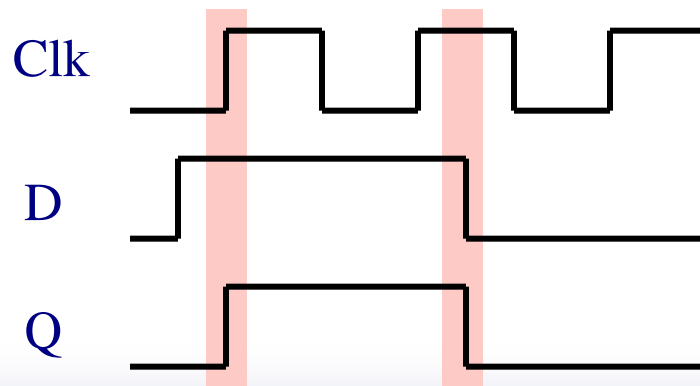
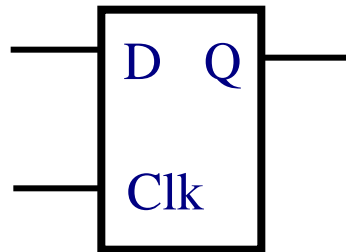
**When clk is low...**

# Latch versus Register

## □ Latch

stores data when  
clock is **high** (or **low**)

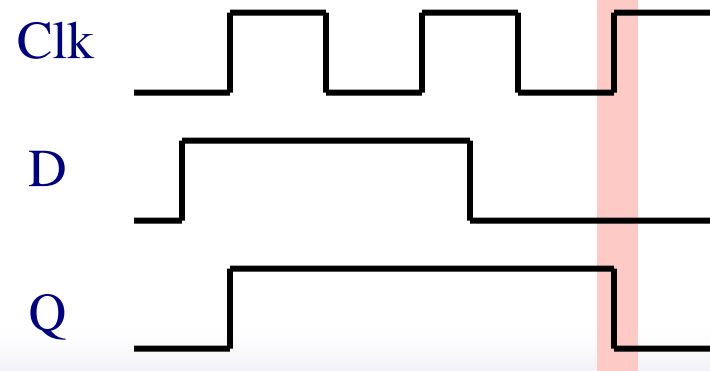
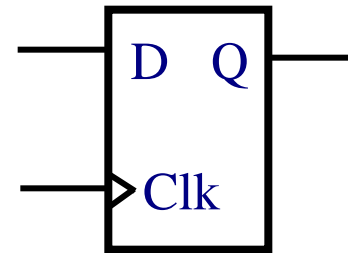
What  
kind of  
latch is  
this?



## □ Register

stores data when  
clock **ris**es (or **fall**s)

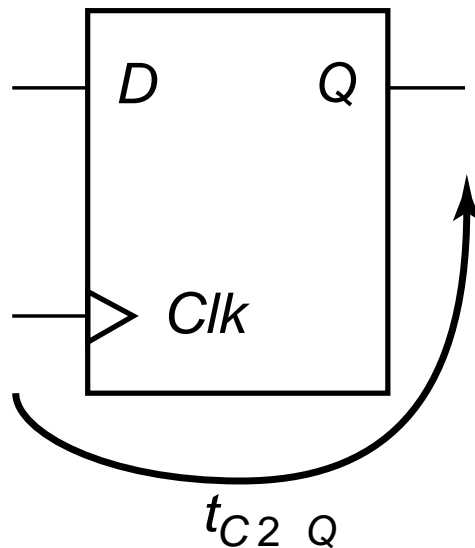
What  
kind of  
Register  
is this?



# Characterizing Timing

## Register

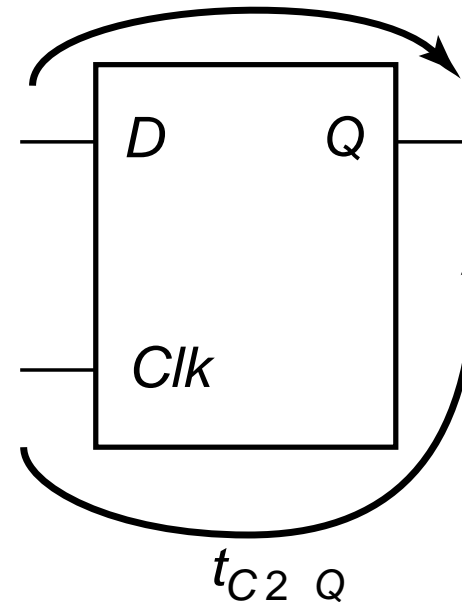
Data is ready when Clk arrives....



## Latch

Requires an extra timing parameter...

$t_{D2Q}$



Data may arrive after Clk edge....

Note: In a **FF**, **D** is valid before **CLK** edge arrives.....hence **only c2q** is relevant.

In a **Latch**, the relevant timing parameter (**c2q** or **d2q**) depends on the **relative position of the arrival of D w.r.t the clk edge**.....if **D** arrives after **clk** edge, then **d2q** is important, while if **D** arrives before **clk** edge, **c2q** is important.

# Registers or Flip-Flops

Combines two latches:

One +ve sensitive (slave) and one -ve sensitive latch (master)

Edge Triggered FF or Master-Slave FF

$CLK=0$ :  $D$  to  $QM$

$$\overline{QM} = \overline{D}$$

Slave holds previous value of  $Q$

$CLK=1$ : master can't sample input and holds value of  $D$

Slave opens and  $QM=(D) = Q$

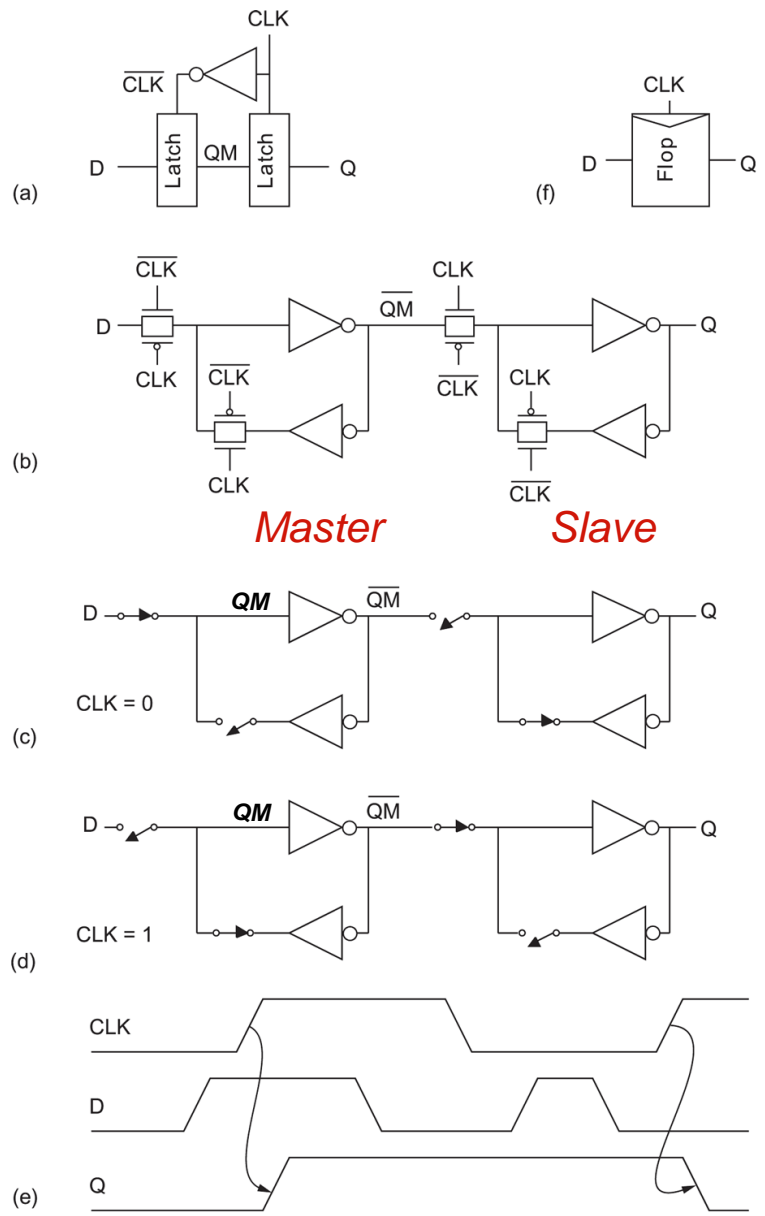
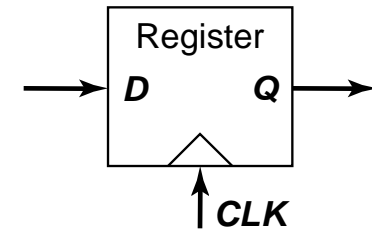
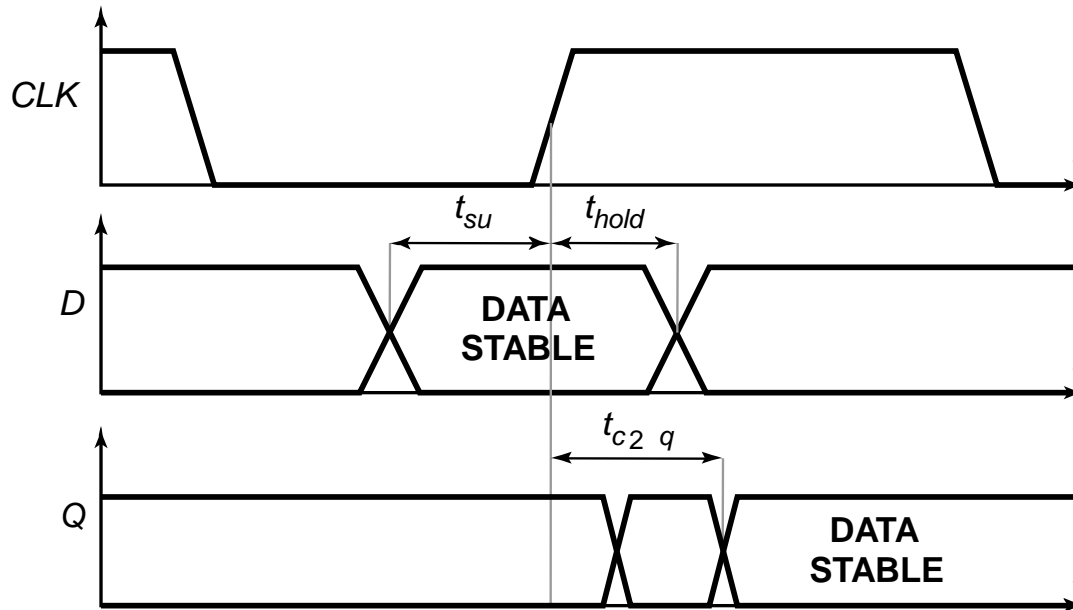


FIG 1.31 CMOS positive-edge-triggered D flip-flop

# Timing Definitions

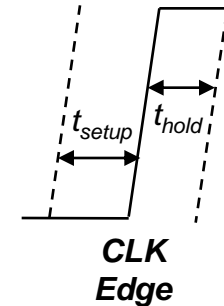
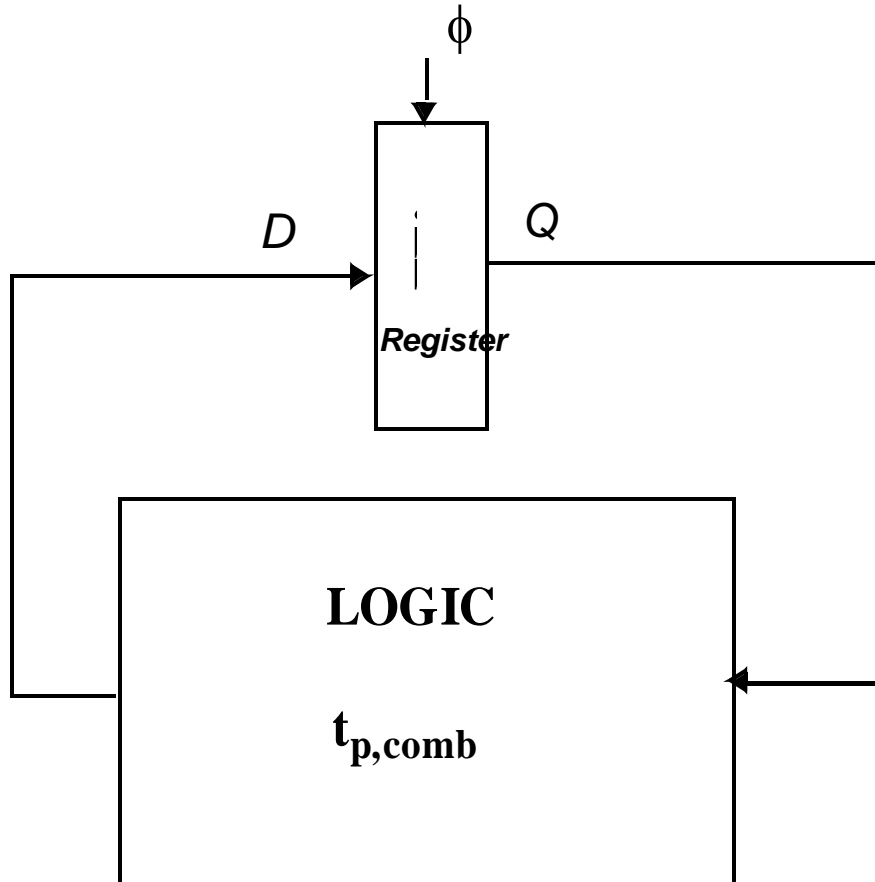


$t_{su}$  = **setup time** = time for which the data inputs (D) must be valid before the CLK edge

$t_{hold}$  = **hold time** = time for which data input must remain valid after the CLK edge

$t_{c2q}$  = **worst case** propagation time through the Register (w.r.t the CLK edge)

# Maximum Clock Frequency



$$2) t_{cdreg} + t_{cdlogic} > t_{hold}$$

$t_{cd}$ : contamination delay = minimum delay

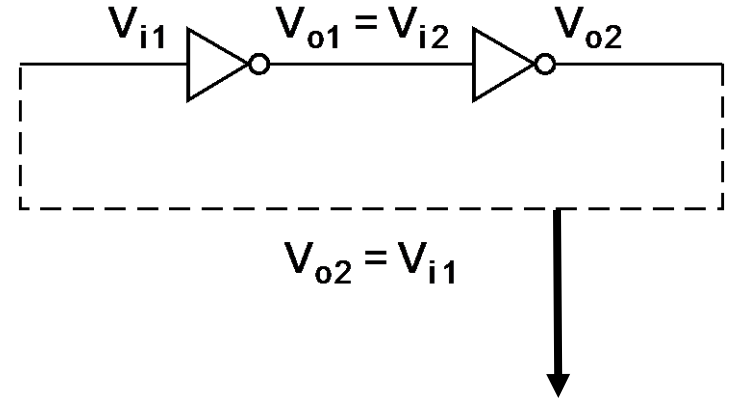
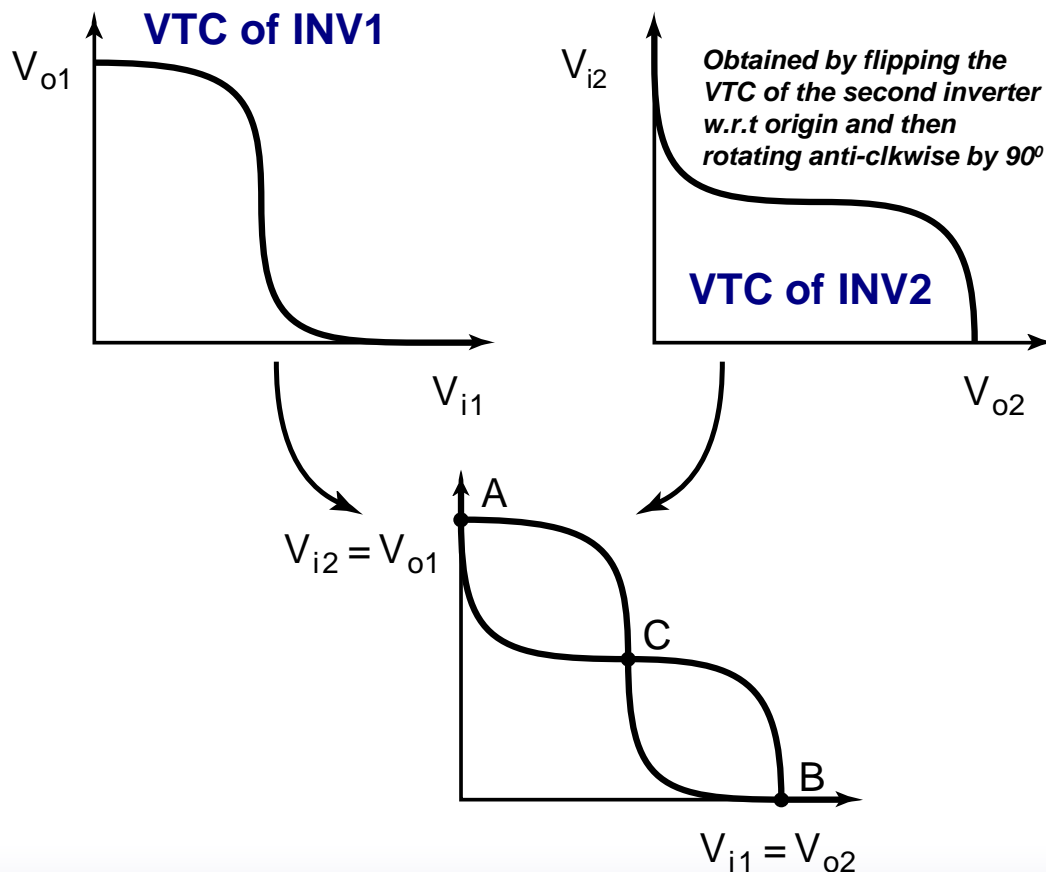
To ensure that the input data of the sequential elements is held long enough after the CLK edge and is not modified too soon by the new wave of data coming in

$$1) T_{min} = t_{clk-Q} + t_{p,comb} + t_{setup}$$

Clk period must accommodate the longest delay of any stage in the network

# Static Latches and Registers

## Static Memories use Positive Feedback: Bi-Stability



*A, B, and C are the only three possible operating points*

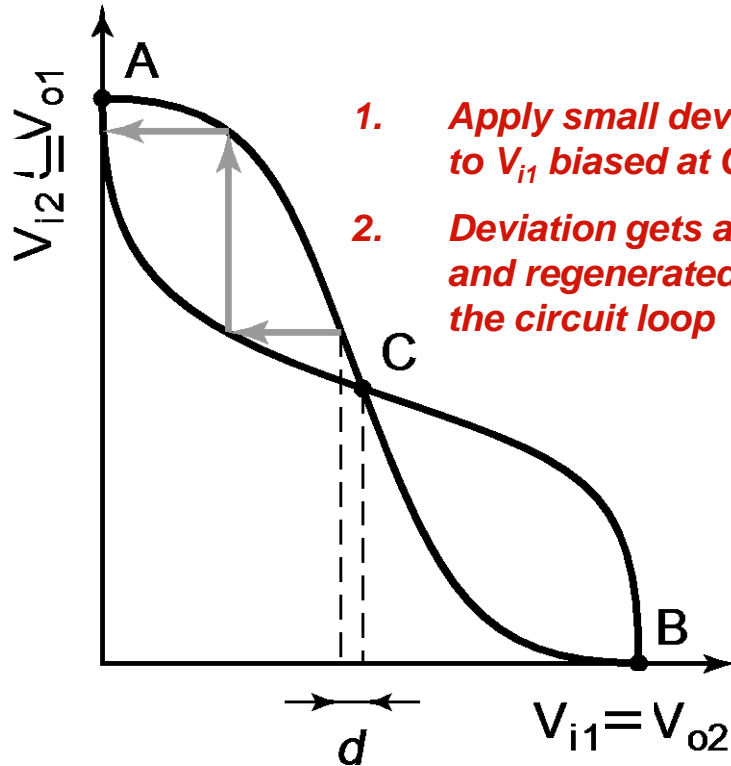
*If gain > 1 in the transient region: A and B are the only stable operating points, C is a metastable point*

**Point C is the  $V_M$  of the Inverters...**



# Meta-Stability in Bi-Stable Circuits

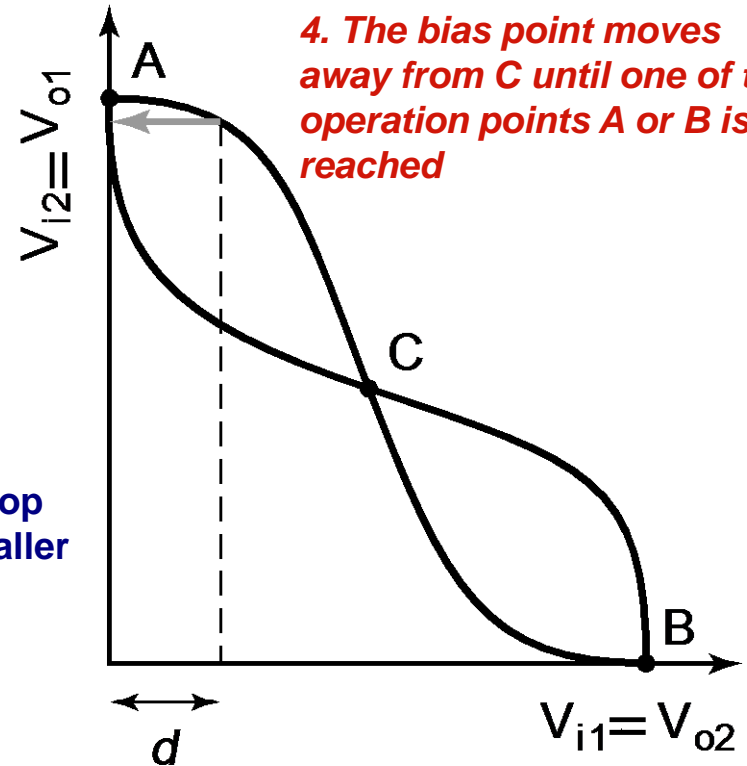
Point C is the  $V_M$  of the Inverters...



1. Apply small deviation  $d$  to  $V_{i1}$  biased at C
2. Deviation gets amplified and regenerated around the circuit loop

At A and B the loop gain is much smaller than 1...hence, stable points

A:  $V_{i1}=0, V_{i2}=1$



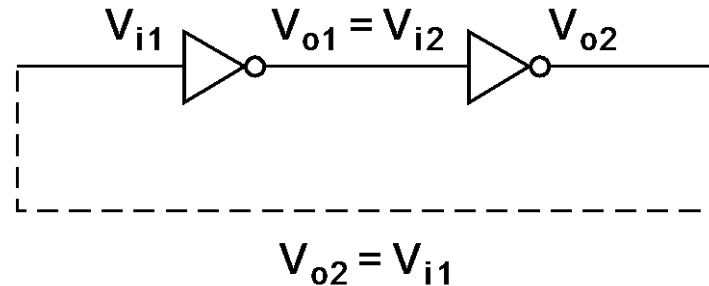
3. Deviation is amplified by the gain of the first inverter and then further amplified by the second inverter

4. The bias point moves away from C until one of the operation points A or B is reached

- Gain is larger than 1 in the transition region
- Every small deviation causes the operation point to move away from its original bias point, C ---therefore metastable

# Flip-Flop

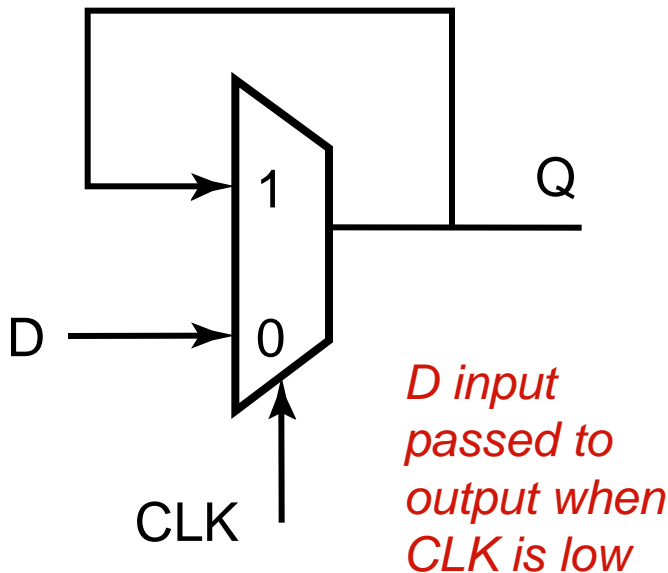
A cross coupled pair of inverters results in a bistable circuit...



- ❑ A FF is a bistable circuit, which has 2 stable states
- ❑ In the absence of triggering the circuit remains in a single state
- ❑ The state can be changed by applying an external trigger
- ❑ Two ways to achieve a change of state:
  - **Cut the feedback loop**: so that a new value can be written into **out** or **Q**
    - This is MUX based:  $Q = \text{CLK} \cdot Q + \text{CLK} \cdot \text{In}$  (most common)
  - **Overpower the feedback loop**
    - Apply a trigger signal at the input of the FF and force the new value into the cell by overpowering the stored value
    - Needs careful sizing of transistors in the feedback loop and the trigger circuit
    - Used mostly in static background memories

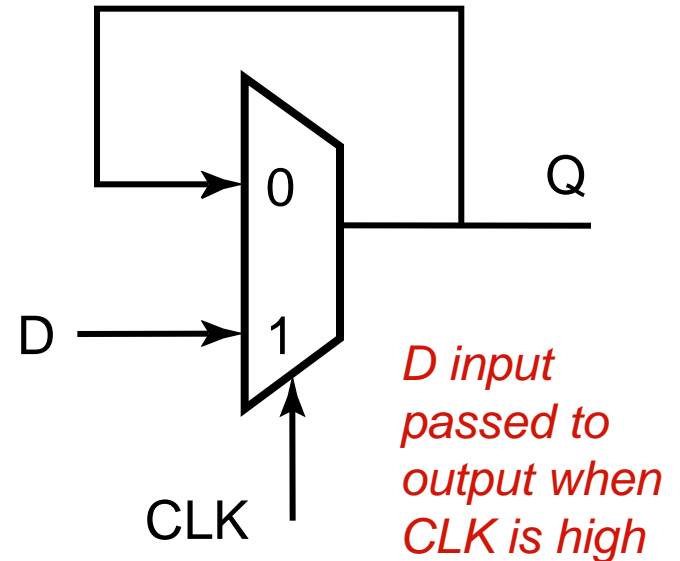
# Mux-Based Latches

Negative latch  
(transparent when CLK= 0)



$$Q = Clk \cdot Q + \overline{Clk} \cdot In$$

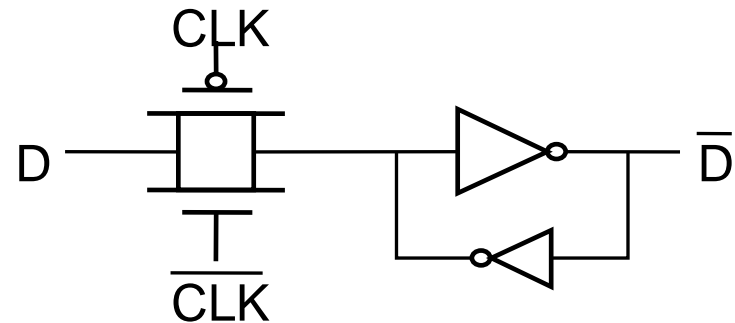
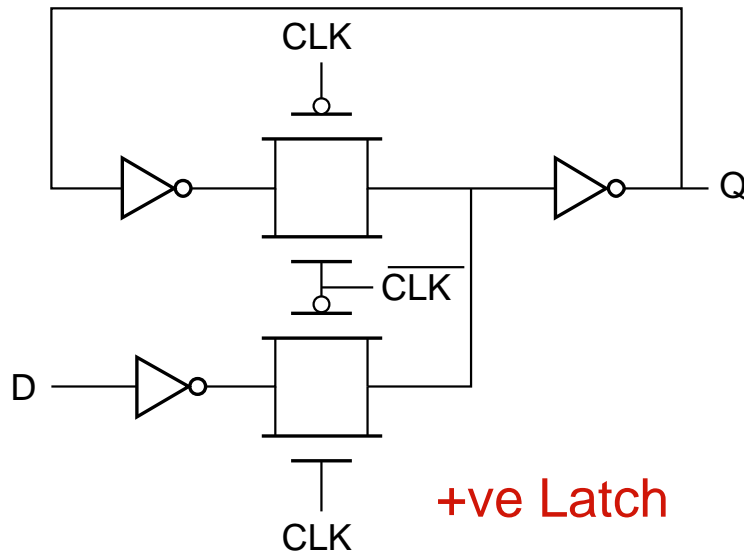
Positive latch  
(transparent when CLK= 1)



$$Q = \overline{Clk} \cdot Q + Clk \cdot In$$

# Writing into a Static Latch

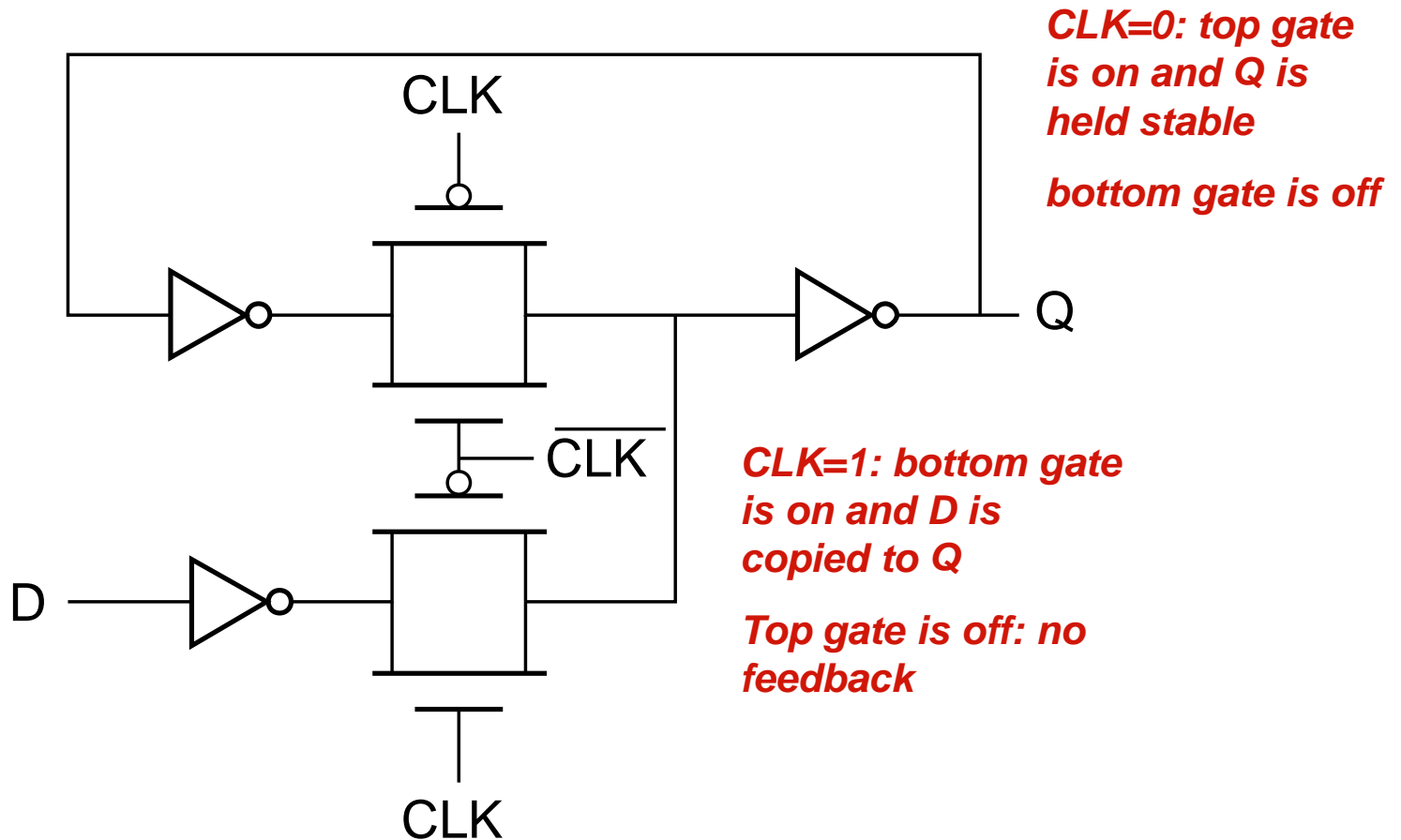
Use the clock as a decoupling signal, that distinguishes between the transparent and opaque states



Forcing the state  
(can implement as NMOS-only)

MUX based (not so efficient....# of transistors driven by CLK is high= 4)

# Mux-Based Latch

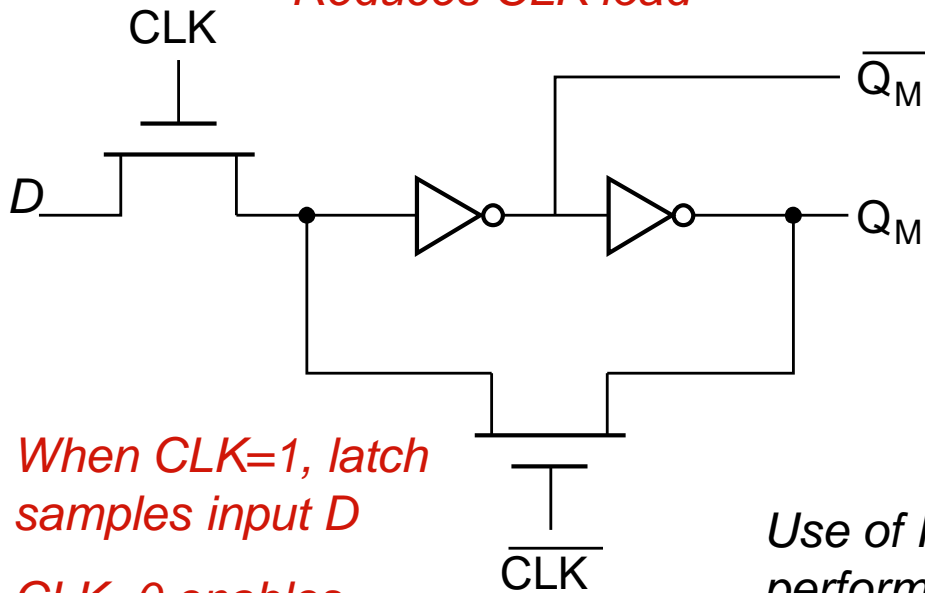


**CLK is driving several transistors with activity=1  
(not good from power perspective!)**

# Mux-Based Latch with Reduced Load

NMOS only Pass Transistor

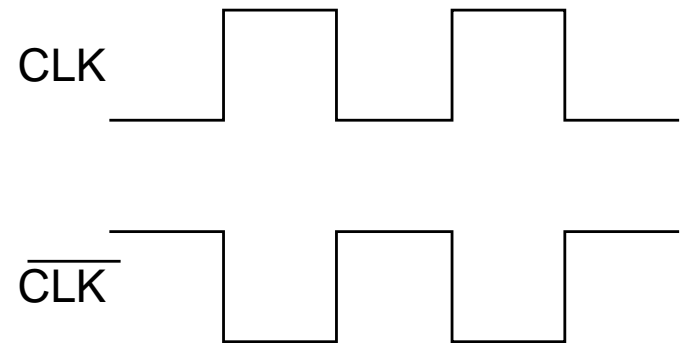
*Reduces CLK load*



*When CLK=1, latch samples input D*

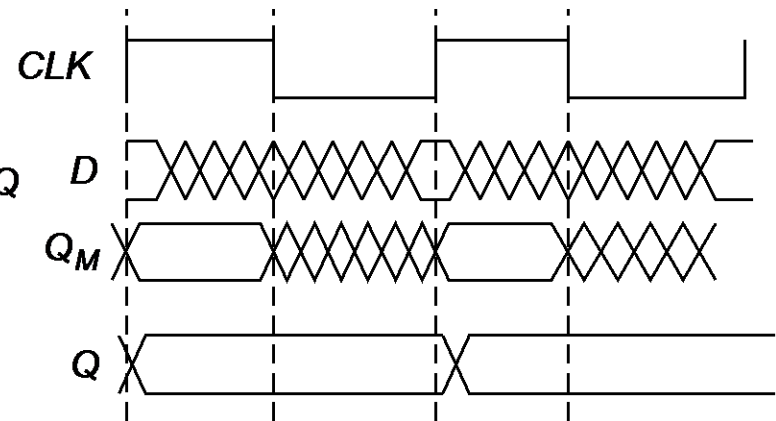
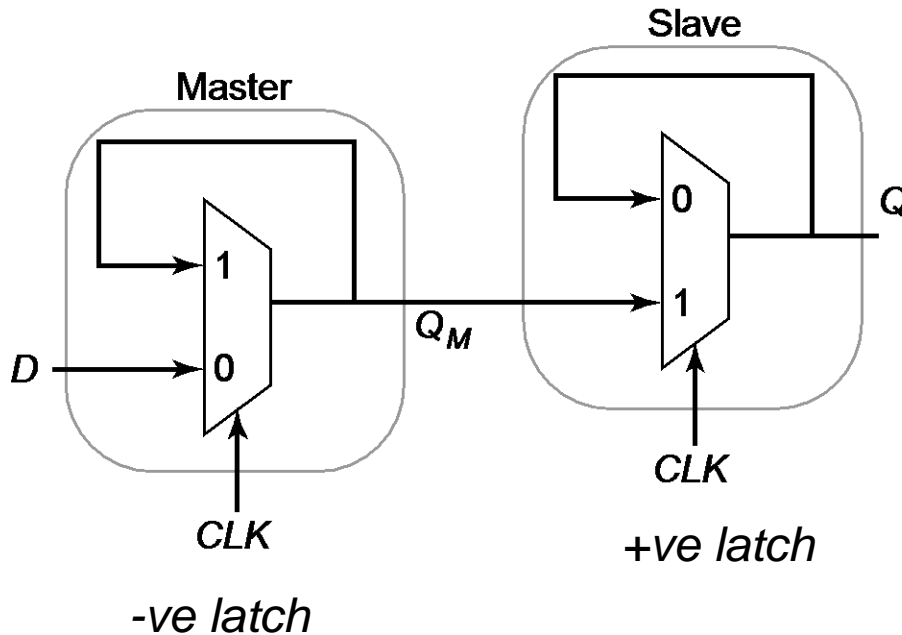
*CLK=0 enables feedback loop, puts latch in hold mode*

Need Non-overlapping clocks



*Use of PT degrades NM and switching performance by passing  $V_{dd} - V_{Tn}$  to the input of first inverter + increases static power (PMOS of inverter is never fully turned off)*

# Master-Slave (Edge-Triggered) Register



**CLK=0: master is transparent and D is copied to  $Q_M$**

**During this time slave is in hold mode**

**As CLK=1: slave starts sampling, master in hold mode**

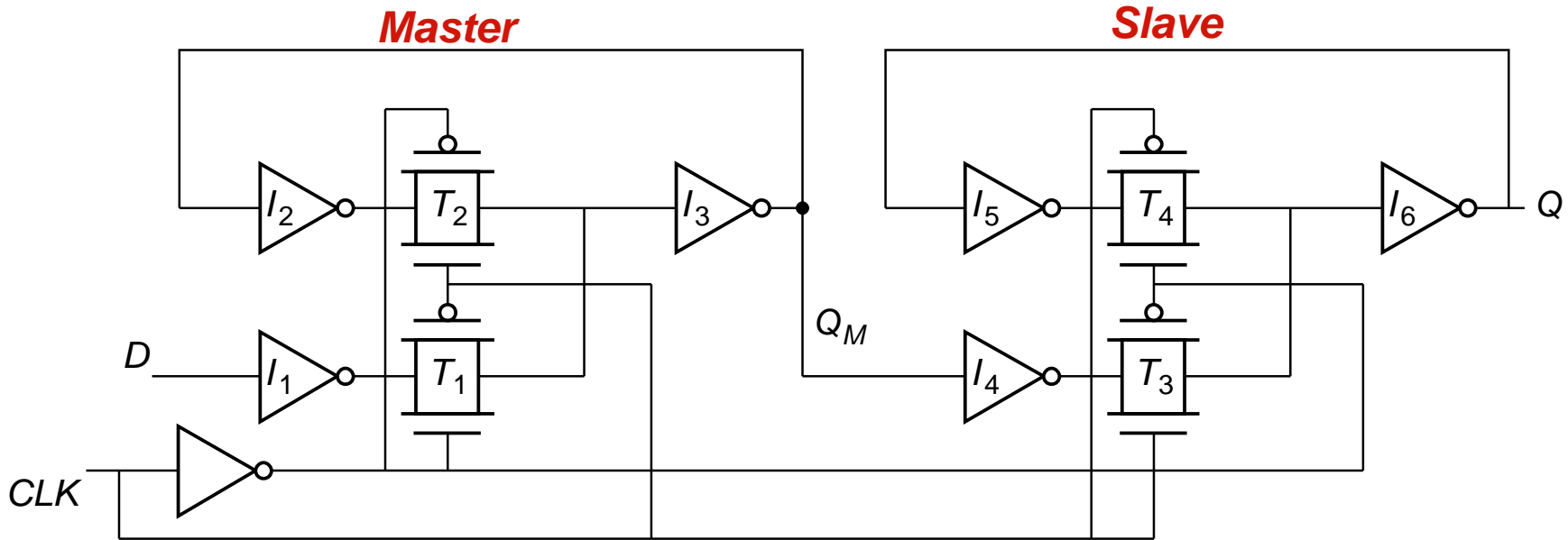
**Value of  $Q$ =Value of D right before the rising edge of the CLK: +ve edge triggered effect**

Two opposite latches trigger on edge  
Also called master-slave latch pair

# Master-Slave +ve Edge Triggered Register

## Transistor Level Implementation

X-gate Multiplexer-based latch pair



**CLK=0:  $T_1$  is on,  $T_2$  is off, D input sampled onto  $Q_M$**

**CLK=1:  $T_3$  is on,  $T_4$  is off,  $Q_M$  sampled onto Q**

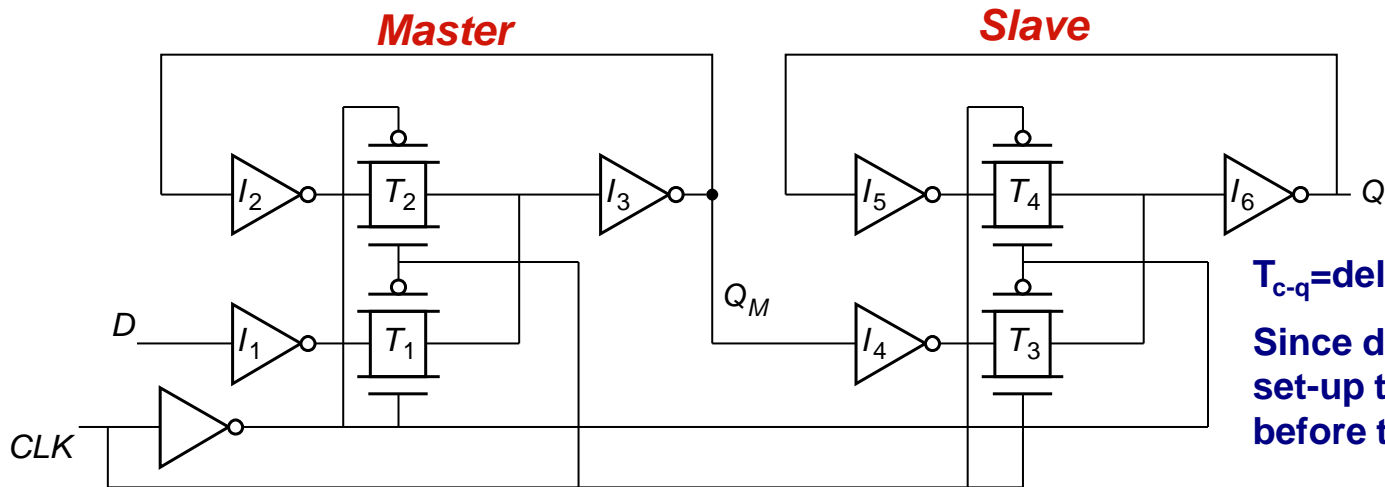
**$T_3$  off and  $T_4$  on:  $I_5$  and  $I_6$  hold the state of the Slave**

**$T_2$  on and  $T_1$  off:  $I_2$  and  $I_3$  hold the state of  $Q_M$**



# Master-Slave +ve Edge Triggered Register

## Transistor Level Implementation



$T_{c-q}$  = delay through T3 and I6

Since delay of I2 is included in set-up time; output of I4 is valid before the rising edge of CLK

$$T_{c-q} = t_{pd\_inv} + t_{pd\_tx}$$

$t_{su}$  = set-up time = time before the rising edge of the CLK during which the D input should remain stable so that QM samples the value reliably

Since D must propagate through I1, T1, I3, and I2 before the rising edge

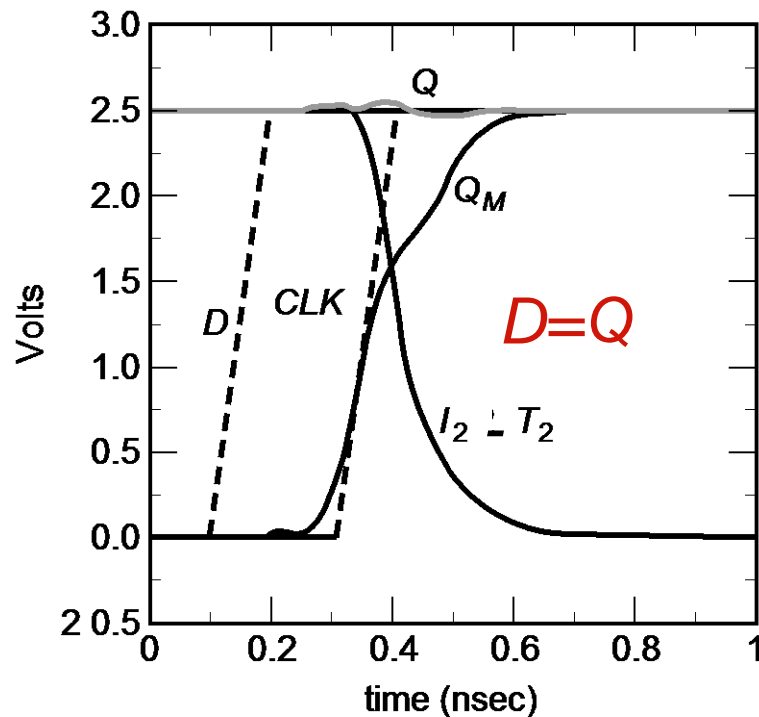
$$t_{su} = 3t_{pd\_inv} + t_{pd\_tx}$$

$$t_{hold} = 0 \text{ (since T1 is cut off after CLK edge)}$$

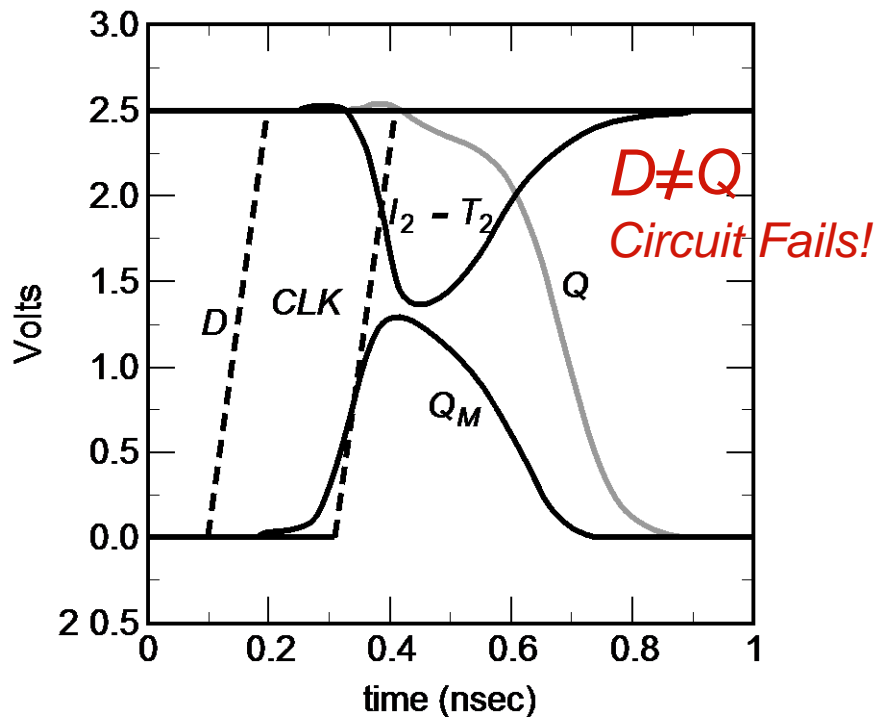
To ensure equal node voltages on both sides of the Xgate

# Timing Analysis: Setup Time

SPICE Simulations: progressively skew the input w.r.t CLK edge until the circuit fails



(a)  $T_{\text{setup}} = 0.21$  nsec



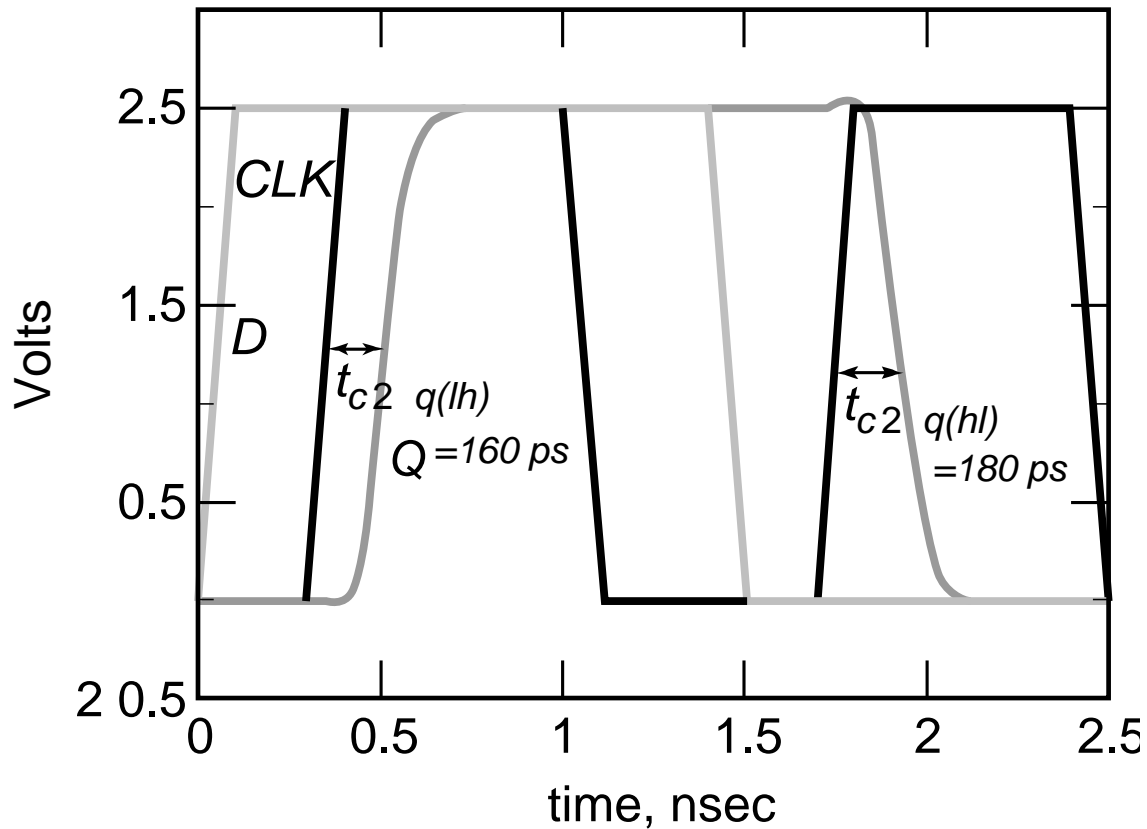
(b)  $T_{\text{setup}} = 0.20$  nsec

*CLK is enabled before the voltage across  $T_2$  settles to the same value*

**Set-up time for this register = 210 ps and hold time = 0**

# Clk-Q Delay

$t_{c-q}$  = 50% point of CLK to 50% point of Q

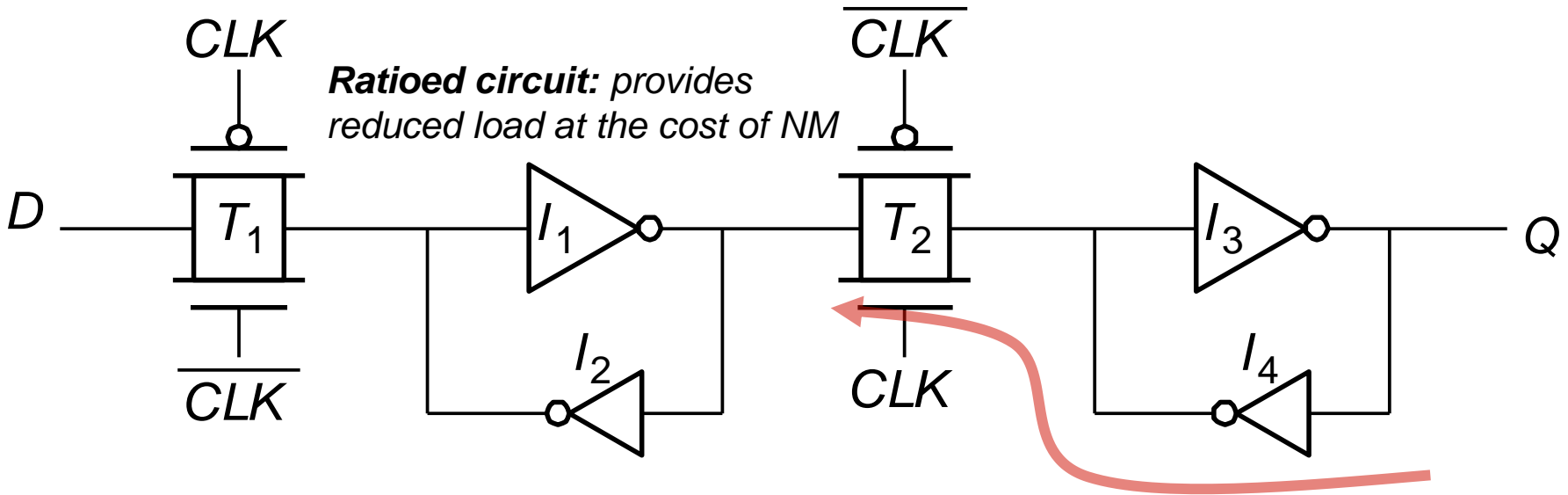


# Reduced Clock Load Master-Slave Register

**Note:** X-gate register presents high capacitive load to the CLK signal

Minimum sized devices are desired for X-gates....why? (CLK power)

However, input to  $I_1$  must be brought below its switching threshold....to make a transition.  
Hence, for minimum sized X-gate,  $I_2$  should be made even weaker.....by increasing  $L_{ch}$ .

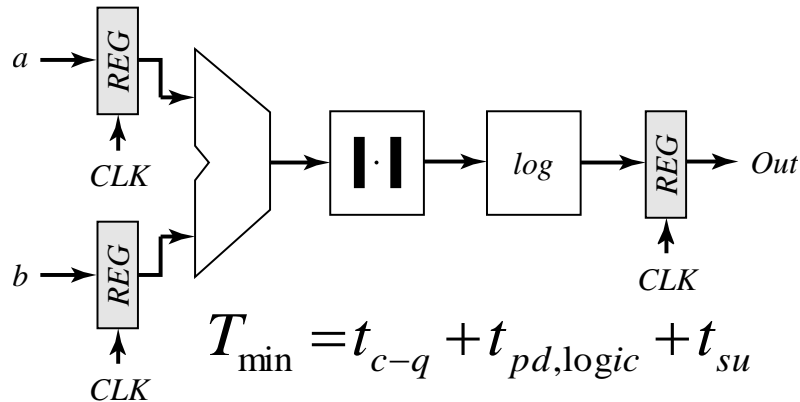


- Cons:** 1)  $T_1$  and its source driver must overpower  $I_2$  to switch the state of the cross-coupled inverter  
2) Reverse conduction---second stage ( $T_2$  and  $I_4$ ) can affect the state of the first latch ( $I_1$ - $I_2$ ) when slave stage is ON....not a major problem if  $I_4$  is weak.

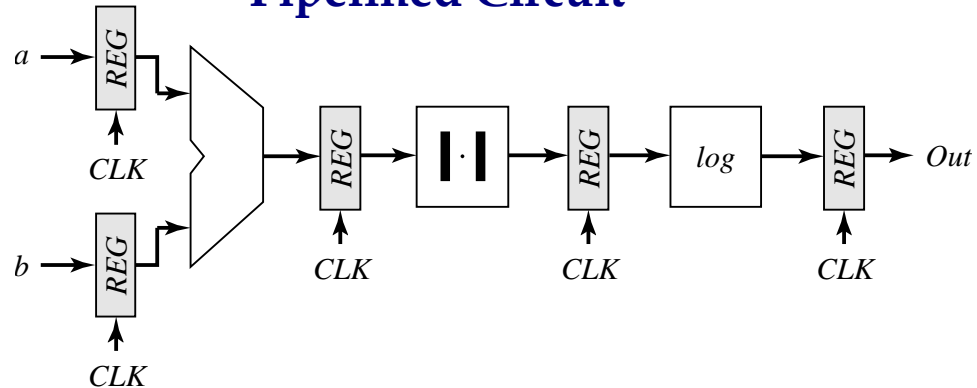
# Pipelining: Optimizing Sequential Circuits

Widely used to accelerate the operation of datapaths in digital microprocessors...

Reference Circuit: computes  $\log(|a+b|)$



Pipelined Circuit



$$T_{\min,pipe} = t_{c-q} + \max(t_{pd,adder} + t_{pd,abs} + t_{pd,log}) + t_{su}$$

Clock Period	Adder	Absolute Value	Logarithm
1	$a_1 + b_1$		
2	$a_2 + b_2$	$ a_1 + b_1 $	
3	$a_3 + b_3$	$ a_2 + b_2 $	$\log( a_1 + b_1 )$
4	$a_4 + b_4$	$ a_3 + b_3 $	$\log( a_2 + b_2 )$
5	$a_5 + b_5$	$ a_4 + b_4 $	$\log( a_3 + b_3 )$

Computation of one set of input data spreads over several clock cycles.

Pipelining improves resource utilization and increases functional throughput.

# Register vs Latch Based Clocking...

- ❑ In an edge-triggered system, the worst case logic path between two registers determines the minimum CLK period for the entire system....
- ❑ If the logic block finishes before the end of the CLK period, it has to sit idle until the next CLK edge...
- ❑ Latch based design offers more flexibility.... one stage can *pass slack* or *borrow time* from other stages...